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DISTRIBUTION STATEMENT A. Approved for public release; distribution is unlimited. **DESC FORM 193**

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1. SCOPE 1.1 Scope. This drawing describes device requirements for class B microcircuits in accordance with 1.2.1 of MIL-STD-883, "Provisions for the use of MIL-STD-883 in conjunction with compliant non-JAN devices". 1.2 Part number. The complete part number shall be as shown in the following example: 5962-87510 Device type Case outline Lead finish per Drawing number (1.2.1)MIL-M-38510 (1.2.2)1.2.1 Device type. The device type shall identify the circuit function as follows: Device type Generic number Circuit function 01 10H589 Hex inverter with enable 1.2.2 Case outlines. The case outlines shall be as designated in appendix C of MIL-M-38510, and as follows: Outline letter Case outline D-2 (16-lead, .840" x .310" x .200"), dual-in-line Ε package F-5 (16-lead, .440" x .285" x .085"), flat package C-2 (20-terminal, .358" x .358" .100"), square chip carrier package 1.3 Absolute maximum ratings. -8.0 V dc to 0.0 V dc 0.0 V dc to -5.2 V dc -65°C to +165°C +300°C Supply voltage range - - - -Input voltage range - - - - - - - - - - -Storage temperature range - - - - - - - - -Lead temperature (soldering, 10 seconds) - - - - -Junction temperature (T_J) - - - - - - - - - - - Maximum power dissipation (P_D) - - - - - - - - Thermal resistance, junction-to-case (θ_{JC}) - - - -+165°C 296 mW See MIL-M-38510, appendix C 1.4 Recommended operating conditions. -5.46 V dc minimum to -4.94 V dc maximum -55°C to +125°C -0.780 V dc -0.650 V dc -0.840 V dc Maximum low-level input voltage (V_{IL})- - - - - - --1.950 V dc SIZE STANDARDIZED 5962-87510 Α MILITARY DRAWING **DEFENSE ELECTRONICS SUPPLY CENTER REVISION LEVEL** SHEET DAYTON, OHIO 45444

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2. APPLICABLE DOCUMENTS

2.1 Government specification and standard. Unless otherwise specified, the following specification and standard, of the issue listed in that issue of the Department of Defense Index of Specifications and Standards specified in the solicitation, form a part of this drawing to the extent specified herein.

SPECIFICATION

MILITARY

MIL-M-38510

- Microcircuits, General Specification for.

STANDARD

MILITARY

MT1.-STD-883

- Test Methods and Procedures for Microelectronics.

(Copies of the specification and standard required by manufacturers in connection with specific acquisition functions should be obtained from the contracting activity or as directed by the contracting activity.)

- 2.2 Order of precedence. In the event of a conflict between the text of this drawing and the references cited herein, the text of this drawing shall take precedence.
 - 3. REQUIREMENTS
- 3.1 Item requirements. The individual item requirements shall be in accordance with 1.2.1 of MIL-STD-883, "Provisions for the use of MIL-STD-883 in conjunction with compliant non-JAN devices" and as specified herein.
- 3.2 Design, construction, and physical dimensions. The design, construction, and physical dimensions shall be as specified in MIL-M-38510 and herein.
 - 3.2.1 Terminal connections. The terminal connections shall be as specified on figure 1.
 - 3.2.2 Truth Table. The truth table shall be as specified on figure 2.
 - 3.2.3 Logic diagram. The logic diagram shall be as specified on figure 3.
 - 3.2.4 Case outlines. The case outlines shall be in accordance with 1.2.2 herein.
- 3.3 Electrical performance characteristics. Unless otherwise specified, the electrical performance characteristics are as specified in table I and apply over the full ambient operating temperature range.
- 3.4 Marking. Marking shall be in accordance with MIL-STD-883 (see 3.1 herein). The part shall be marked with the part number listed in 1.2 herein. In addition, the manufacturer's part number may also be marked as listed in 6.4 herein.
- 3.5 Certificate of compliance. A certificate of compliance shall be required from a manufacturer in order to be listed as an approved source of supply in 6.4. The certificate of compliance submitted to DESC-ECS prior to listing as an approved source of supply shall state that the manufacturer's product meets the requirements of MIL-STD-883 (see 3.1 herein) and the requirements herein.
- 3.6 Certificate of conformance. A certificate of conformance as required in MIL-STD-883 (see 3.1 herein) shall be provided with each lot of microcircuits delivered to this drawing.

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	T .	Condi	tions			Lin	nits	
Test	Symbol 	-55°C < TA Unless other	<pre> < +125°C wise spec </pre>	ified	Group A subgroups	Min	Max	Unit
Cases E, F, and 2		Quiesce	nt tests	1/				
High level output voltage	V _{OH}	Outputs terminated through 100Ω to -2 V V _{CC} = 0.0 V	V _{IH} -0.780 -0.650 -0.840	V _{IL} -1.950 -1.950 -1.950		-0.860	-0.780 -0.650 -0.840	V
Low level output voltage	i v _{ol}	VEE = -5.2 V 2/	-0.780 -0.650 -0.840	-1.950 -1.950 -1.950	2	-1.950	-1.580 -1.565 -1.610	l V
High level threshold output voltage	V _{OHA}] - - -	-1.110 -0.960 -1.160	-1.480 -1.465 -1.510		-0.860	-0.780 -0.650 -0.840	١٧
Low level threshold output voltage	VOLA	 	-1.110 -0.960 -1.160	-1.480 -1.465 -1.510	1 2 3	-1.950	-1.580 -1.565 -1.610	ĺ۷
Power supply drain current	IEE		at +25°C at +125°C at -55°C	C	2,3	-42 -46		mA
High level input current	IIH				1,2		310 495	μ Α
Low level input current	IIL	VEE = -4.94 V VIL = -1.950 V VCC = 0.0 V			1,3		0.5	μ Α μ Α
See footnotes at end of tabl	e.							
STANDARDIZE	_	SIZE A			596	2-87510		
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TABLE I.	Electi	rical p	performance	characte	ristics -	Continued.			
Test	Symbol	 -! Un	Condit 55°C < TA < less other	< +125°C	fied	 Group A subgroups		iits Max	Unit
Cases E and F	! <u></u>	<u> </u>	Rap	id tests <u>3</u>	<u> </u>	<u> </u>			
High level output voltage	V _{OH}	thro	inated	V _{IH} -0.793 -0.664 -0.854	V _{IL} -1.950 -1.950 -1.950		1-0.873	 -0.793 -0.664 -0.854	٧
Low level output voltage	V _{OL}	VFF :	= -5.2 V 2/	-0.793 -0.664 -0.854	-1.950 -1.950 -1.950	1 2	1.950	-1.584 -1.569 -1.614	٧
High level threshold output voltage	V _{OHA}	1		-1.122 -0.973 -1.173	-1.484 -1.469 -1.514		-0.873	 -0.793 -0.664 -0.854	
Low level threshold output voltage	V _{OLA}	 		-1.122 -0.973 -1.173		1 2 3	-1.950	-1.584 -1.569 -1.614	٧
Power supply drain current	I _{EE}	I Vcc	= -5.46 V = 0.0 V = -0.793 V -0.664 V -0.854 V	at +25°C at +125°C at -55°C		1 2,3	 -41 -45 	[mA
High level input current	IIH	- 				1,2		 295 480	μ Α
Low level input current	I IIL	VII	= -4.94 V = -1.950 V = 0.0 V			1,3	 	0.5	μ Α μ Α
See footnotes at end of tabl	е.								
STANDARDIZEI MILITARY DRAW		:	SIZE A	:		596	2-87510	1	-
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		Condi	tions			Limits			
Test	Symbol 	-55°C < T _A Unless other 	<pre></pre>	ified	Group A subgroups 	Min	Max	Unit	
Case 2		Rap	id tests	_					
High level output voltage	V _{OH}	Outputs terminated through 100Ω to -2 V V _{CC} = 0.0 V	V _{IH} -0.799 -0.670 -0.860	V _{IL} -1.950 -1.950 -1.950	j 2	-0.879	-0.799 -0.670 -0.860	V	
Low level output voltage	V _{OL}	VEE = -5.2 V VEE = -5.2 V 2/	-0.799 -0.670 -0.860	-1.950 -1.950 -1.950	j 2 '	-1.950	-1.586 -1.571 -1.616	V	
High level threshold output voltage	V _{OHA}		-1.127 -0.979 -1.179	l-1.471	1 2 3	-0.879	-0.799 -0.670 -0.860	٧	
Low level threshold output voltage	V _{OLA}	; 	-1.127 -0.979 -1.179	-1.486 -1.471 -1.516		-1.950	-1.586 -1.571 -1.616	٧	
Power supply drain current	IEE	V _{EE} = -5.46 V V _{CC} = 0.0 V V _{IH} = -0.799 V -0.670 V -0.860 V		-41 -45		mA			
High level input current	IIH				1,2		295 480	μА	
Low level input current	IIL	V _{EE} = -4.94 V V _{IL} = -1.950 V V _{CC} = 0.0 V	ı		1,3	 	0.5	μ Α μ Α 	
See footnotes at end of tab		SIZE			596	2-87510			
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		Conditions		Lin	<u>.</u>	
Test	Symbol	Conditions -55°C < T _A < +125°C Unless otherwise specified	Group A	Min	Max	⊤ Unit
Cases E, F, and 2		AC tests			•	<u> </u>
Transition time	It _{TLH} ,	V _{EE} = -2.94 V	9	0.70	2.40	ns
Transicion cime	ItTHL	V _{CC} = 2.0 V	10	0.70	2.40	1
	, INC	C _i < 5 pF	11	0.70	2.20	ļ
		RL = 100Ω		0.70	1.80	ns
Propagation delay time,	ļtрнн,	<u>4</u> /	10		1.90	1 113
A to Y	tpLL		111	0.70	1.90	i
			11	0.70	1 1.90	ĺ
Propagation delay time,	Ito. u		9	0.70	2.50	ns
E to Y	ltpLH, ltpHL		10	0.70	2.80	1
L 00 .	THL		11	0.70	2.20	

- 1/ The quiescent limits are determined after a device has reached thermal equilibrium. This is defined as the reading taken with the device in a socket with > 500 LFPM of +25°C, +125°C, or -55°C (as applicable), air blowing on the unit in a transverse direction with power applied for at least 4 minutes before the reading is taken. This method was used for theoretical limit establishment only. All devices shall be tested to the delta V (rapid test) conditions specified herein. The rapid test method is an equivalent method of testing quiescent conditions.
- 2/ The high and low level output current varies with temperature and can be calculated using the following formula: I_{OH} = (V_{OH} -2 V)/100 Ω ; I_{OL} = (V_{OL} -2 V)/100 Ω .
- 3/ The dc rapid test forcing functions and limits are used for all dc testing. These limits are determined for each device type based on the power dissipation and package type. The rapid test (delta Y) limits and forcing functions are skewed allowing rapid testing to be performed at standard temperatures without the addition of delta T's.
- 4/ The load circuit shall consist of the output under test going through R_L to GND and through C_L to the tester. C_L includes scope probe, wiring, and stray capacitance without the package in the test fixture. $t_{\text{PL}L}$ shall be measured from the midpoint of a low input to the midpoint of a low output. t_{PLH} shall be measured from the midpoint of a high input to the midpoint of a high output. t_{PLH} and t_{PHL} voltage waveforms shall be in accordance with method 3003 of MIL-STD-883, with threshold voltage points at 50%. t_{TLH} and t_{THL} voltage waveforms shall be in accordance with method 3004 of MIL-STD-883, with measurement points at 20% and 80%.
- 3.7 Notification of change. Notification of change to DESC-ECS shall be required in accordance with MIL-STD-883 (see 3.1 herein).
- 3.8 Verification and review. DESC, DESC's agent, and the acquiring activity retain the option to review the manufacturer's facility and applicable required documentation. Offshore documentation shall be made available onshore at the option of the reviewer.
 - 4. QUALITY ASSURANCE PROVISIONS
- 4.1 Sampling and inspection. Sampling and inspection procedures shall be in accordance with section 4 of MIL-M-38510 to the extent specified in MIL-STD-883 (see 3.1 herein).

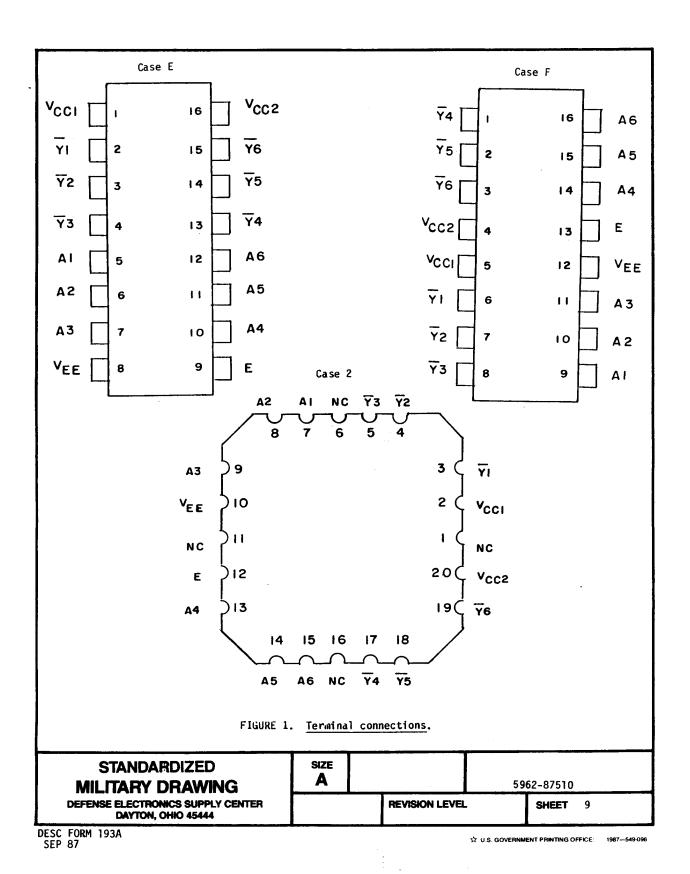
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TABLE II. Electrical test requirements.

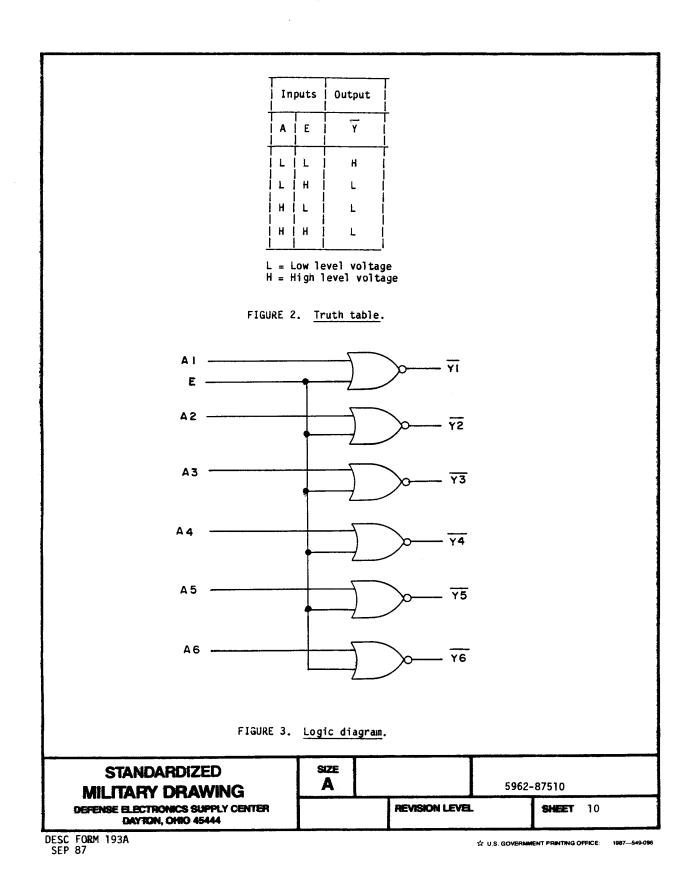
MIL-STD-883 test requirements	Subgroups (per method 5005, table I)
Interim electrical parameters (method 5004)	1
Final electrical test parameters (method 5004)	1*, 2, 3, 7*, 9
Group A test requirements (method 5005)	1, 2, 3, 7, 9, 1 10, 11
Groups C and D end-point electrical parameters (method 5005)	1, 2, 3

- * PDA applies to subgroups 1 and 7.
- 4.2 <u>Screening</u>. Screening shall be in accordance with method 5004 of MIL-STD-883, and shall be conducted on all devices prior to quality conformance inspection. The following additional criteria shall apply:
 - a. Burn-in test, method 1015 of MIL-STD-883.
 - (1) Test condition A, B, C, or D using the circuit submitted with the certificate of compliance (see 3.5 herein).
 - (2) $T_A = +125^{\circ}C$, minimum.
 - b. Interim and final electrical test parameters shall be as specified in table II herein, except interim electrical parameter tests prior to burn-in are optional at the discretion of the manufacturer.
- 4.3 Quality conformance inspection. Quality conformance inspection shall be in accordance with method 5005 of MIL-STD-883 including groups A, B, C, and D inspections. The following additional criteria shall apply.
 - 4.3.1 Group A inspection.
 - a. Tests shall be as specified in table II herein.
 - b. Subgroups 4, 5, 6, and 8 in table I, method 5005 of MIL-STD-883 shall be omitted.
 - c. Subgroup 7 tests shall verify the truth table specified on figure 2 herein.
 - 4.3.2 Groups C and D inspections.
 - a. End-point electrical parameters shall be as specified in table II herein.
 - b. Steady-state life test conditions, method 1005 of MIL-STD-883.
 - (1) Test condition A, B, C, or D using the circuit submitted with the certificate of compliance (see 3.5 herein).

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- (2) $T_A = +125$ °C, minimum.
- (3) Test duration: 1,000 hours, except as permitted by method 1005 of MIL-STD-883.
- 5. PACKAGING
- 5.1 Packaging requirements. The requirements for packaging shall be in accordance with MIL-M-38510.
 - 6. NOTES
- 6.1 Intended use. Microcircuits conforming to this drawing are intended for use when military specifications do not exist and qualified military devices that will perform the required function are not available for OEM application. When a military specification exists and the product covered by this drawing has been qualified for listing on QPL-38510, the device specified herein will be inactivated and will not be used for new design. The QPL-38510 product shall be the preferred item for all applications.
- 6.2 Replaceability. Microcircuits covered by this drawing will replace the same generic device covered by a contractor-prepared specification or drawing.
- 6.3 <u>Comments</u>. Comments on this drawing should be directed to DESC-ECS, Dayton, Ohio 45444, or telephone 513-296-5375.
- 6.4 Approved source of supply. An approved source of supply is listed herein. Additional sources will be added as they become available. The vendor listed herein has agreed to this drawing and a certificate of compliance (see 3.5 herein) has been submitted to DESC-ECS.

Military drawing part number	Vendor CAGE number	Vendor similar part number <u>1</u> /
5962-8751001EX	04713	10H589/BEAJC
5962-8751001FX	04713	10H589/BFAJC
5962-87510012X	04713	10H589M/B2CJC

 $\frac{1}{acquisition}.$ Do not use this number for item acquisition. Items acquired to this number may not satisfy the performance requirements of this drawing.

Vendor CAGE number

Vendor name : and address

04713

Motorola, Incorporated 7402 South Price Road Tempe, AZ 85283

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